



GAN 1703

PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

~~SECRET~~ Recipient: Katsumi Sameshima  
Serial No.: 09451,979

Examiner: Unassigned

Serial No.: 09-451,979

Group Art Unit: 1753

Filed: November 30, 1999

Docket: 362-39

**For: FERROELECTRIC MEMORY AND  
METHOD FOR  
MANUFACTURING SAME**

Dated: May 2, 2000

**Assistant Commissioner for Patents  
Washington, DC 20231**

## **INFORMATION DISCLOSURE STATEMENT**

Sii.

In order to fulfill the requirements of candor and good faith set forth in 37 C.F.R. §1.56, Applicant submits herewith the following Information Disclosure Statement in accordance with the provisions of 37 C.F.R. §1.97 and §1.98.

## U. S. PATENTS

<u>Patentee</u>	<u>Patent No.</u>	<u>Issue Date</u>
✓SL Sakao	5,652,446	July 29, 1997
✓SL New	5,801,916	September 1, 1998

## **FOREIGN PATENT DOCUMENTS**

<u>Country</u>	<u>Publication/Application No.</u>	<u>Publication Date</u>
Patent Abstracts of Japan	05327062	December 10, 1993
Patent Abstracts of Japan	11251549	September 17, 1999
Europe	EP 0 697 719 (A2)	February 21, 1996
Europe	EP0 886 317 (A2)	December 23, 1998

I hereby certify this correspondence is being deposited with the United States Postal Service as first class mail, postpaid in an envelope, addressed to: Assistant Commissioner for Patents, Washington, D.C.

May 2, 2000

Date: 1/13/2000

Susan L. Toledano

Susan L. Toledano